

St. Xavier's College

Dr. Camil Bulcke Path, Ranchi

Faculty Profile

Name of Faculty Member : Dr. Ravi Kumar Bommali

Gender : Male

Email ID : ravibommali06@gmail.com

Name of Department : Department of Physics

Designation : Assistant Professor

Level of Teaching : Undergraduate

Academic Qualification : M.Sc., Ph.D.

Total Teaching Experience : 5 Years and 8 Months

UGC NET/SET Qualified : Yes

Research Papers Published:

- 1) H Gupta, <u>RK Bommali</u>, S Ghosh, H Srivastava, A Srivastava, P Srivastava, "Correlation between changes in nanoscale structural and optical properties upon swift heavy ion irradiation of SiN_x thin films", *Journal of Applied Physics*. 3 (2021) 035108.
- 2) H. Gupta O. Plantevin R. K. Bommali Santanu Ghosh Pankaj Srivastava, "A Study of Temperature-Dependent Photoluminescence from As-Deposited and Heavy-Ion-Irradiated Plasma-Enhanced Chemical Vapor Deposition-Grown Si-Rich a-SiNx: H Thin Films", Phys. Status Solidi B (2020), 1900378.
- 3) R. K. Bommali et al. "Angle dependent localized surface plasmon resonance from silver nanoparticles embedded in SiO2 thin film", Journal of Applied Physics. 124 (2018) 063107.
- 4) Alejandro F.Braña, Harsh Gupta, <u>R. K.Bommali</u> et al. "Enhancing efficiency of c-Si solar cell by coating nano structured silicon rich silicon nitride films Thin Solid Films" 662 (2018)21.

- 5) R. K. Bommali et al. "Hydrogen loss and its improved retention in hydrogen plasma treated a-SiNx:H films: ERDA study with 100 MeV Ag7+ ions", Nuclear Instruments and Methods in Physics Research Section B 423 (2018)16-21
- 6) Harsh Gupta, <u>RK Bommali</u> et al. "**Stabilization of Si rich nitride phase by swift** heavy ion irradiation in non-stoichiometric a-SiNx: H thin films", *Nuclear Instruments and Methods in Physics Research Section B* 410 (2017) 164-170
- 7) R. K. Bommali, S. Ghosh and P. Srivastava "Evolution of a dense interlayer in a-SiNx:H thin films under 100 MeV Ni7+ ion irradiation", AIP Conference Proceedings 1832 (2017) 080088
- 8) Vinod Parmar, Pawan Kumar Kanaujia, <u>R.K.Bommali</u>, G. Vijaya Prakash "Efficient Surface Enhanced Raman Scattering substrates from femtosecond laser based fabrication", *Optical Materials* 72 (2017) 86-90
- 9) V Parmar, PK Kanaujia, <u>RK Bommali</u>, GV Prakash "Femtosecond Laser Based Fabrication of Nanostructured Silicon" International Conference on Fibre Optics and Photonics, W3A. 91, (2016)
- 10) R. K. Bommali *et al.*, "Swift heavy ion irradiation induced microstructural modification and evolution of photoluminescence from Si rich a-SiNx:H" *Mater. Res. Express* 2 (2015) 046204
- 11) R. K. Bommali et al., "Narrow band Photocurrent response from partially phase separated a-SiNx:H thin films", Journal of Applied Physics. 116 (2014) 113501.
- 12) R. K. Bommali et al., "Hydrogen plasma induced modification of photoluminescence from a-SiNx:H thin films", Journal of Applied Physics. 115 (2014) 053525.
- 13) R. K. Bommali et al., "Study of Growth Kinetics and Depth Resolved Composition of a-SiNx:H Thin Films by Resonant Soft X-Ray Reflectivity at the Si L2,3-Edge", Applied Surface Science. 305 (2014)173.
- 14) R. K. Bommali et al., "Excitation dependent photoluminescence study of Sirich a-SiNx:H thin films", Journal of Applied Physics. 112 (2012)123518.
- 15) R. K. Bommali et al., "Growth and Tailoring of Physical Properties of Si Quantum Dots in a-SiNx:H Matrix", Energy Procedia. 41 (2013) 50.

Participation in UGC-HRDC Course/FDP/OC/RC:

1) Completed the 17th Faculty Induction Programme, conducted by HRDC Ranchi in online mode between, 4th -31st August 2023

Seminar/Conference attended/Paper Presented (National/International):

- 1) INUP-i2i familiarization workshop on Nanofabrication and Characterization, June 28th -30th 2023, Conducted by IIT Kharagpur in online mode.
- 2) R K Bommali et al. "Silver implanted silicon oxide and nitride thin films with tunable plasmonic properties" ICNIB-2021, Institute of Physics Bhubaneswar 5th to 8th October 2021 (Flash Presentation).
- 3) Workshop on Evidence based teaching and learning strategies in higher education, between July 13th 15th conducted by CREATES, IISER Bhopal.
- 4) R K Bommali et al "Near-surface incorporation of Silver ions in silicon oxide/nitride dielectrics for tunable plasmonic properties" EMSI-2018 18th to 20th July 2018 (Poster).
- 5) R K Bommali et al., "Near-surface incorporation of Silver ions in silicon oxide/nitride dielectrics for tunable plasmonic properties" ICMAT-2017, Singapore 18th to 24th June 2017 (Poster).
- 6) R K Bommali et al., "Tunable Opto-electrical properties from partially phase separated a-SiNx:H thin films" ETAFM-2016: Emerging trends in Advanced Functional Materials, Institute of Physics Bhubaneswar, 18th to 21st Jan 2016 (Poster).
- 7) R K Bommali et al., "Slow and fast diffusion processes in a-SiNx:H thin films during MeV Ag ion irradiation", Joint ICTP-IAEA Advanced Workshop on High Sensitivity 2D & 3D Characterisation and Imaging with Ion Beams, ICTP, Treiste, Italy 25th to 30th Sept 2016 ICTP.
- 8) R K Bommali et al., "UV dominated photoresponse from substoichiometric PECVD Silicon Nitride films" International Conference on Solar Energy Photovoltaic- Bhubaneswar 17th 19th Dec 2016 (Poster).
- 9) R K Bommali et al., "Evolution of a dense interlayer in a-SiNx:H thin films under 100 MeV Ni⁷⁺ ion irradiation" DAE- Solid State Physics Symposium 26th to 30th Dec 2016 KIIT University Bhubaneswar (Poster).
- 10) R K Bommali et al., "Growth & Modification of Si rich Silicon Nitride for Solar cell applications" group progress reappraisal at the 3rd IAEA Coordinated Research for CRP-F12024 meeting held in Pretoria, South Africa 13th to 17th April 2015. (Oral).
- 11) R. K. Bommali et al., "Tunable opto-electrical properties from partially phase separated a-SiNx:H thin films" ICOOPMA-2014: International Conference on Optical, Optoelectronic and Photonic Materials and Applications, University of Leeds, Leeds UK 27th July -1st August. (Oral).

- 12) R. K. Bommali et al., "Swift Heavy Ion Irradiation induced modification in Si rich a-SiN_x:H thin films", ICNIB-2013: International Conference on Nanostructuring by Ion Beams, Rajasthan University, Jaipur, India (Best Poster).
- 13) R. K. Bommali et al., "Si Rich Silicon Nitride: A Material with Tunable Optoelectrical properties", IUMRS-ICA 2013: International Union of Materials Research Society of India-International conference of Asia, IISc Bangalore, India 16th-20th December 2013. (Oral).
- 14) R. K. Bommali et al. "Growth and Tailoring of physical properties of Si-QDs in a-SiNx:H films", Energy-2012 International workshop on the modification and analysis of materials for future energy sources, Autonoma de Madrid, Spain 17th to 20th September 2012. (Oral).

Any Special Award/Achievement:

- 1) National Postdoctoral Fellow (DST-SERB India) (July 2017-June2018) at the Institute of Physics Bhubaneswar, Odisha, India.
- 2) Additional Scientific Investigator (2012 to April-2015) in the project titled, "Si quantum dots on Silicon nitride as anti-reflection coatings of third generation solar cell: role of hydrogen". This project was funded by the *IAEA Coordinated Research Project- F12024*; aimed at promoting the use of ion beams for research and fomenting collaborations between various member nations.

[Dr. Ravi Kumar Bommali]